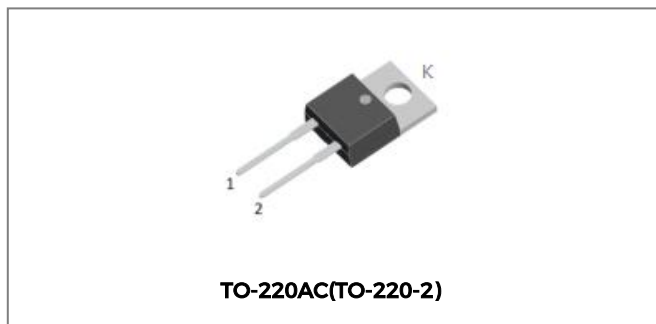


S6D02065A

650V SIC POWER SCHOTTKY RECTIFIERS



Description

This 650V 2A diode is a high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S6D02065A is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Features

- 175°C TJ operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- “-A” is an AEC-Q101 qualified device
- Pb - Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Maximum Ratings:

| Characteristics | Symbol | Condition | Max. | Units |
|---|--------------|--|------|-------|
| Peak Repetitive Reverse Voltage | V_{RRM} | - | 650 | V |
| Working Peak Reverse Voltage | V_{RWM} | | | |
| DC Blocking Voltage | V_{DC} | | | |
| Average Rectified Forward Current | $I_{F(AV)1}$ | $T_C = 25^\circ\text{C}$ | 13 | A |
| | $I_{F(AV)2}$ | $T_C = 165^\circ\text{C}$ | 2 | A |
| Repetitive Peak Forward Surge Current | I_{FRM1} | 10ms, Half Sine pulse, $T_C = 25^\circ\text{C}$ | 12 | A |
| | I_{FRM2} | 10ms, Half Sine pulse, $T_C = 110^\circ\text{C}$ | 9 | A |
| Peak One Cycle Non-Repetitive Surge Current | I_{FSM1} | 10ms, Half Sine pulse, $T_C = 25^\circ\text{C}$ | 20 | A |
| | I_{FSM2} | 10ms, Half Sine pulse, $T_C = 110^\circ\text{C}$ | 15 | A |
| Power Dissipation | P_{tot1} | $T_C = 25^\circ\text{C}$ | 63 | W |
| | P_{tot2} | $T_C = 110^\circ\text{C}$ | 27 | W |

Electrical Characteristics:

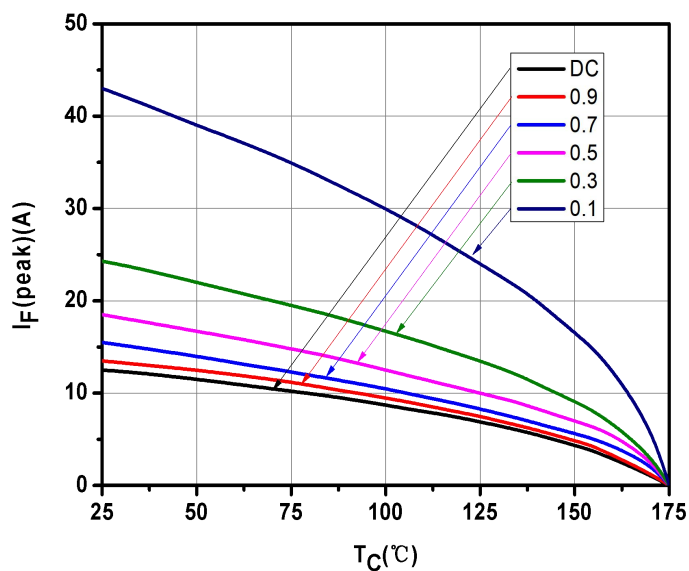
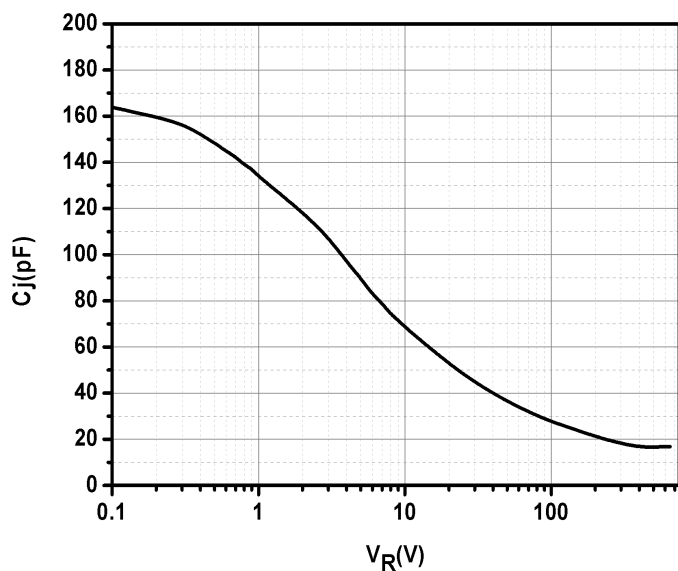
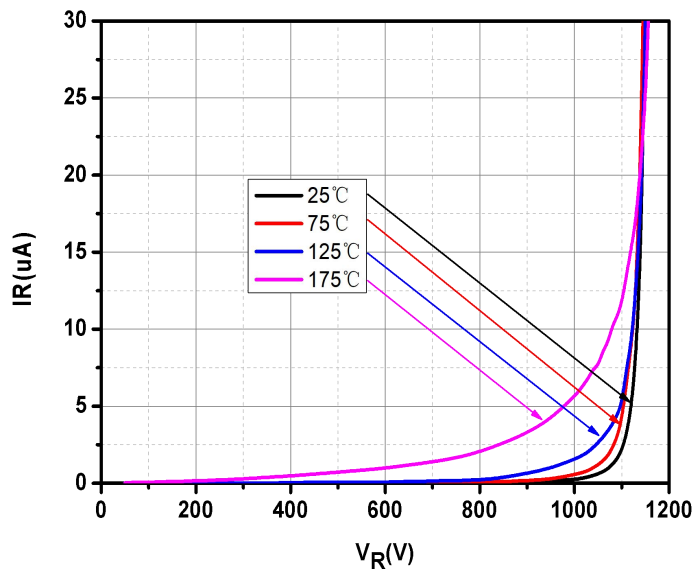
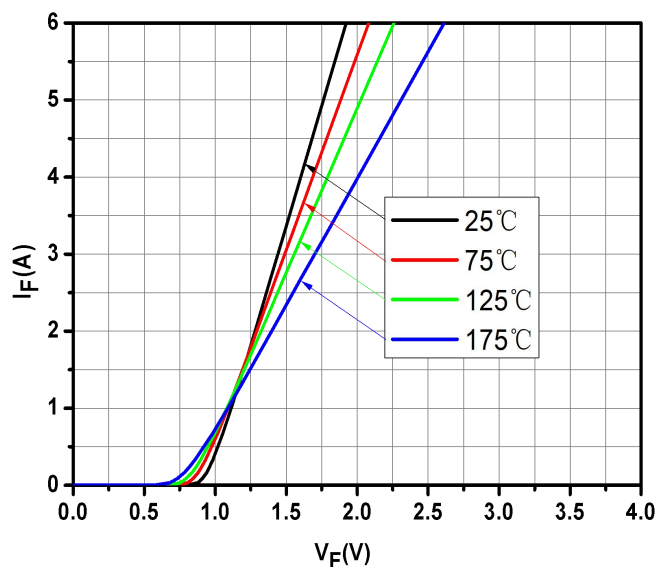
| Characteristics | Symbol | Condition | Typ. | Max. | Units |
|----------------------------------|----------|---|-------|------|---------------|
| Forward Voltage Drop* | V_{F1} | @ 2A, Pulse, $T_J = 25^\circ\text{C}$ | 1.27 | 1.5 | V |
| | V_{F2} | @ 2A, Pulse, $T_J = 175^\circ\text{C}$ | 1.4 | 1.6 | V |
| Reverse Current at DC condition* | I_{R1} | @ $V_R = \text{rated } V_R$ $T_J = 25^\circ\text{C}$ | 0.3 | 3 | μA |
| Reverse Current * | I_{R2} | @ $V_R = \text{rated } V_R$ $T_J = 175^\circ\text{C}$ | 6 | 25 | μA |
| Junction Capacitance | C_T | $V_R = 0\text{V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{MHz}$ | 170 | - | pF |
| Reverse Recovery Charge | Q_c | $I_F = 2\text{A}$, $di/dt = 200\text{A}/\mu\text{s}$ $V_R = 400\text{V}$, $T_J = 25^\circ\text{C}$ | 10.60 | - | nC |
| Capacitance Stored Energy | E_C | $V_R = 400\text{V}$, $T_J = 25^\circ\text{C}$ | 2.60 | - | μJ |

* Pulse width < 300 μs , duty cycle < 2%

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|-----------------|--------------|---------------|---------------------------|
| Junction Temperature | T_J | - | -55 to +175 | $^\circ\text{C}$ |
| Storage Temperature | T_{stg} | - | -55 to +175 | $^\circ\text{C}$ |
| Typical Thermal Resistance Junction to Case | $R_{\theta JC}$ | DC operation | 2.4 | $^\circ\text{C}/\text{W}$ |

Ratings and Characteristics Curves



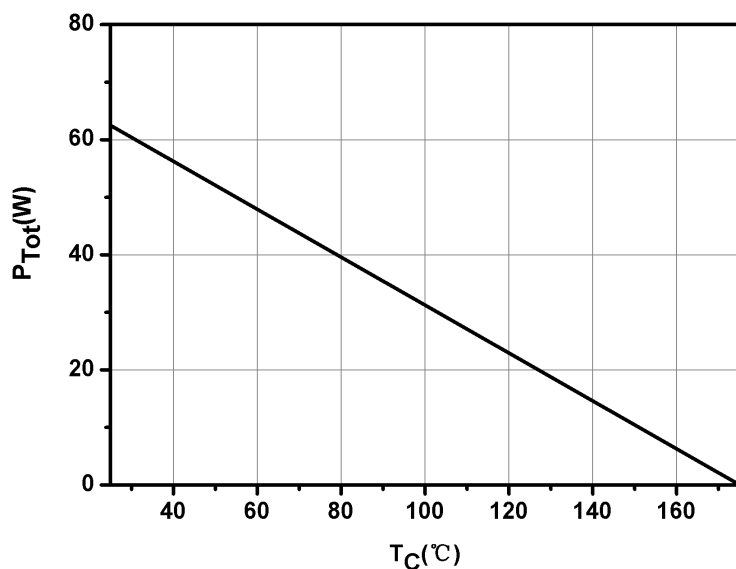


Fig.5-Power Derating

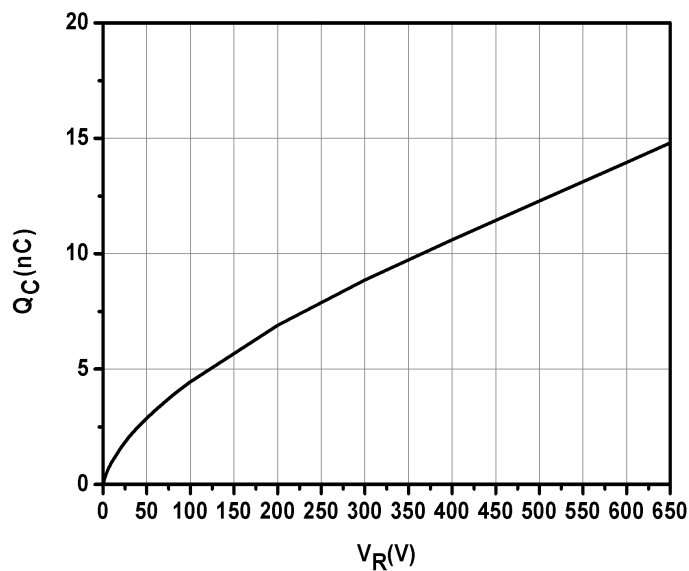


Fig.6-Total Capacitance Charge vs. Reverse Voltage

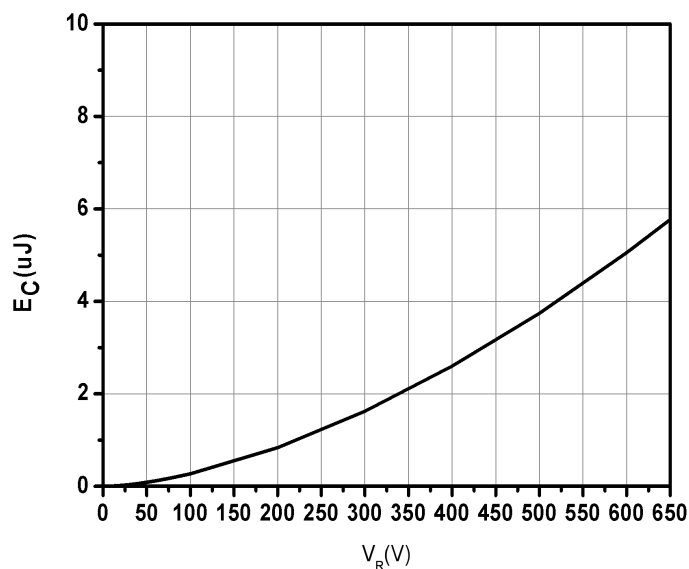
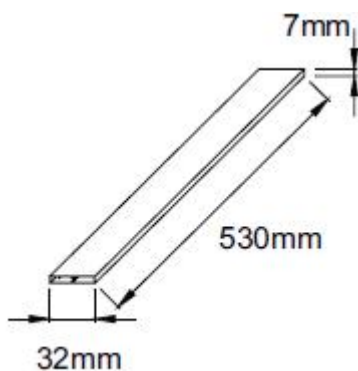


Fig.7-Capacitance Stored Energy vs. Reverse Voltage

Ordering Information

| Device | Package | Shipping |
|-----------|--------------------|-------------|
| S6D02065A | TO-220AC(TO-220-2) | 50pcs /tube |

Tube Specification



Marking Diagram

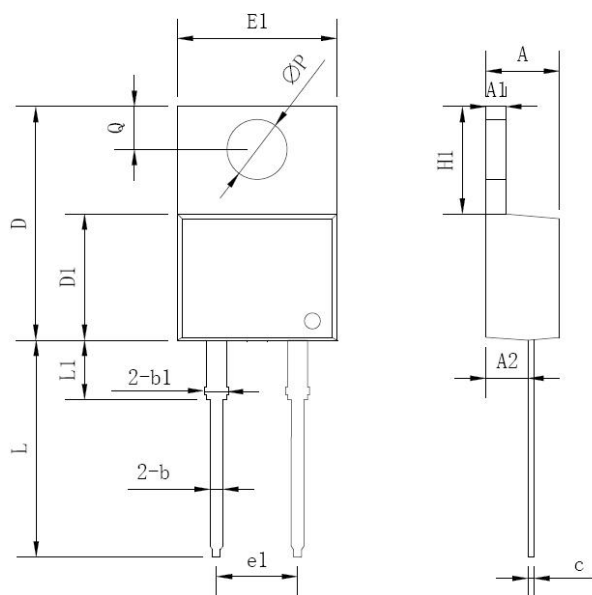


Where XXXXX is YYWWL

S6D = Device Type
A = Package type
02 = Forward Current (50A)
065 = Reverse Voltage (650V)
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions : Molding resin
Epoxy resin UL : 94V-0

Mechanical Dimensions



| Symbol | Dimensions in millimeters | | |
|--------|---------------------------|---------|-------|
| | Min. | Typical | Max. |
| A | 3.56 | - | 4.83 |
| A1 | 0.51 | - | 1.40 |
| A2 | 2.03 | - | 2.92 |
| b | 0.38 | - | 1.02 |
| b1 | 1.14 | - | 1.78 |
| c | 0.31 | - | 0.61 |
| D | 14.22 | - | 16.51 |
| D1 | 8.38 | - | 9.42 |
| E1 | 9.65 | 10.16 | 10.67 |
| e1 | - | 5.08 | - |
| H1 | 5.84 | - | 6.86 |
| L | 12.70 | - | 14.73 |
| L1 | - | - | 6.35 |
| ΦP | - | 3.56 | - |
| Q | 2.54 | - | 3.43 |

Technical Data
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